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Vishay Semiconductors

www.vishay.com

Ultrafast Rectifier, 20 A FRED Pt[®]





PRIMARY CHARACTERISTICS					
I _{F(AV)}	20 A				
V _R	600 V				
V _F at I _F	1.26 V				
t _{rr} (typ.)	61 ns				
T _J max.	175 °C				
Package	2L TO-220 FullPAK				
Circuit configuration	Single				

FEATURES

- Low forward voltage drop
- · Ultrafast soft recovery time
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package (V_{INS} = 2500 V_{BMS})
- Designed and gualified according to JEDEC[®]-JESD 47
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

Ultralow V_F, soft-switching ultrafast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

APPLICATIONS

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage	V _{RRM}		600	V			
Average rectified forward current in DC	I _{F(AV)}	T _C = 102 °C	20	А			
Non-repetitive peak surge current	I _{FSM}	$T_J = 25 \ ^{\circ}C$	190	A			
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-		
Forward voltage	VF	I _F = 20 A	-	1.4	1.63	V	
VF VF		I _F = 20 A, T _J = 125 °C	-	1.26	1.49		
Poverse leakage ourrent	1	$V_R = V_R$ rated	-	0.3	15		
Reverse leakage current	I _R	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	50	500	μA	
Junction capacitance	CT	V _R = 600 V	-	18	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH	

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RoHS

COMPLIANT

HALOGEN FREE

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST	MIN.	TYP.	MAX.	UNITS	
Reverse recovery time	+	T _J = 25 °C	I _F = 20 A dI _F /dt = 1000 A/μs V _B = 400 V	-	61	-	ns
neverse recovery time	t _{rr}	T _J = 125 °C		-	87	-	
Peak recovery current		T _J = 25 °C		-	13	-	А
Peak recovery current	IRRM	T _J = 125 °C		-	21	-	A
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	480	-	nC
		T _J = 125 °C		-	1080	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C
Thermal resistance, junction to case	R _{thJC}		-	2.5	3	
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	70	°C/W
Typical thermal resistance, case to heatsink	R _{thCS}	thCS Mounting surface, flat, smooth, and greased		0.5	-	
Wainht			-	2	-	g
Weight			-	0.07	-	oz.
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style: 2L TO-220 FullPAK E4TU2006FP				

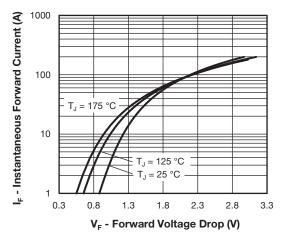


Fig. 1 - Typical Forward Voltage Drop Characteristics

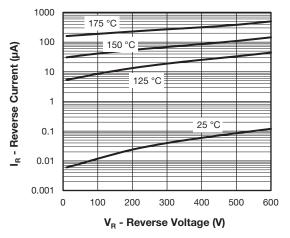


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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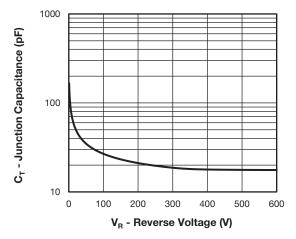


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

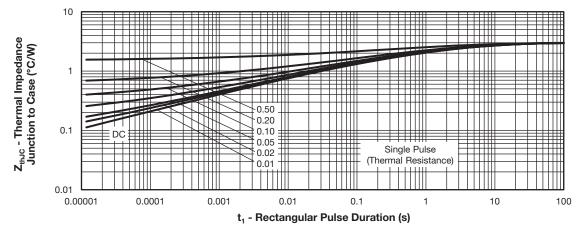
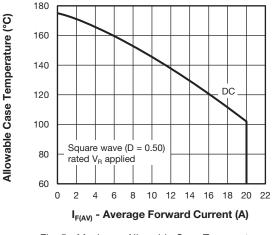
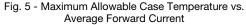


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics





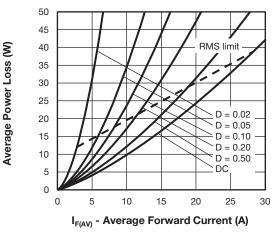


Fig. 6 - Forward Power Loss Characteristics

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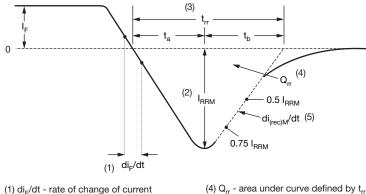


Fig. 7 - Reverse Recovery Waveform and Definitions

- through zero crossing
- (2) I_{RBM} peak reverse recovery current
- $\begin{array}{l} \text{(3) } t_{rr} \text{ reverse recovery time measured} \\ \text{from zero crossing point of negative} \\ \text{going I}_{\text{F}} \text{ to point where a line passing} \\ \text{through } 0.75 \text{ I}_{\text{RRM}} \text{ and } 0.50 \text{ I}_{\text{RRM}} \\ \text{extrapolated to zero current.} \end{array}$

(4) ${\rm Q}_{\rm rr}$ - area under curve defined by ${\rm t}_{\rm rr}$ and ${\rm I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE

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Device code	VS-	E	4	т	U	20	06	FP	-N3
	1	2	3	4	5	6	7	8	9
	1	J J							
	3 4	- 4 =	E = single diode 4 = Gen 4 FRED Pt T = TO-220						
	5 · 6 ·		U = ultrafast recovery time Current code: 20 = 20 A						
	7 · 8 ·		Voltage code: 06 = 600 V FP = FullPAK						
	9			ntal digit gen-free		complia	ant, and	totally I	ead (Pb)

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-E4TU2006FP-N3	50	1000	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?96157						
Part marking information	www.vishay.com/doc?95392					

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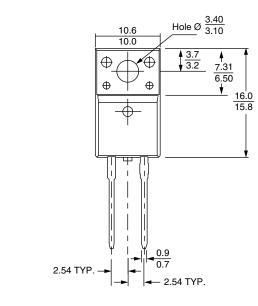
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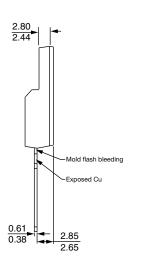


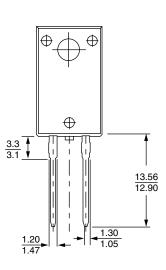
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2L TO-220 FullPAK

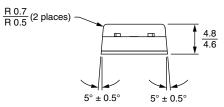
DIMENSIONS in millimeters







Bottom view





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